

# Thyristor/Thyristor (Super MAGN-A-PAK Power Modules), 570 A



Super MAGN-A-PAK

PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	570 A			
Туре	Modules - thyristor, standard			
Package	Super MAGN-A-PAK			

#### **FEATURES**

- · High current capability
- High surge capability
- · Industrial standard package
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

- Motor starters
- DC motor controls AC motor controls
- Uninterruptible power supplies

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>T(AV)</sub>	T <sub>C</sub> = 85 °C	570			
I <sub>T(RMS)</sub>	T <sub>C</sub> = 85 °C	894	Α		
I <sub>TSM</sub>	50 Hz	18 000	A		
	60 Hz	18 800			
l <sup>2</sup> t	50 Hz	1620	kA <sup>2</sup> s		
	60 Hz	1473	KA-S		
I <sup>2</sup> √t		16 200	kA <sup>2√</sup> s		
V <sub>DRM</sub> /V <sub>RRM</sub>		1600	V		
T <sub>Stg</sub>	Range	-40 to +125	°C		
T <sub>J</sub>	Range	-40 to +135	C		

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}/I_{DRM}$ MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA		
VS-VSKT570-16PbF	16	1600	1700	110		



PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current		1000			570 85	Α
at case temperature	I <sub>T(AV)</sub>	180° conduction	on, half sine wave			°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	180° conduction	on, half sine wave	at T <sub>C</sub> = 85 °C	894	Α
		t = 10 ms	No voltage		18.0	
Maximum peak, one-cycle,	I <sub>TSM.</sub>	t = 8.3 ms	reapplied	Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	18.8	kA kA <sup>2</sup> s
non-repetitive on-state surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RBM</sub>		15.1	
		t = 8.3 ms	reapplied		15.8	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	No voltage reapplied		1620	
	l <sup>2</sup> t	t = 8.3 ms			1473	
		t = 10 ms	100 % V <sub>RBM</sub>		1146	
		t = 8.3 ms	reapplied		1042	
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		16 200	kA²√s	
Low level value or threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			0.59	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.63	v
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			0.41	mΩ
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.38	1115.2	
Maximum on-state voltage drop	V <sub>TM</sub>	$I_{pk}$ = 1500 A, $T_J$ = 25 °C, $t_p$ = 10 ms sine pulse			1.36	V
Maximum holding current	I <sub>H</sub>	T _ 05 °C	ada aupply 10 V ==	pointive load	500	
Maximum latching current	ΙL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		1000	- mA	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum rate of rise of turned-on current	dl/dt	$T_J = T_J$ maximum, $I_{TM} = 400$ A, $V_{DRM}$ applied	1000	A/µs	
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	2.0		
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 750 A; $T_J$ = $T_J$ maximum, $dI/dt$ = - 60 A/ $\mu$ s, $V_R$ = 50 V, $dV/dt$ = 20 V/ $\mu$ s, gate 0 V 100 $\Omega$	65 to 240	μs	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to $V_D = 80 \% V_{DRM}$	1000	V/µs	
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V	
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	110	mA	



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $t_p \le 5$ ms	10	W	
Maximum peak average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$	2.0	] VV	
Maximum peak positive gate current	+I <sub>GM</sub>		3.0	Α	
Maximum peak positive gate voltage	+V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	20	V	
Maximum peak negative gate voltage	-V <sub>GM</sub>		5.0		
Maximum DC gate current required to trigger	I <sub>GT</sub>	T 05 °C V 10 V	200	mA	
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C, V <sub>ak</sub> 12 V	3.0	V	
DC gate current not to trigger	$I_{GD}$	$T_J = T_J$ maximum	10	mA	
DC gate voltage not to trigger	$V_{GD}$		0.25	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	TJ		-40 to +135	°C
Maximum storage temperature range	T <sub>Stg</sub>		-40 to +125	
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.06	14004
Maximum thermal resistance, case to heatsink per module	R <sub>thC-hs</sub>	R <sub>thC-hs</sub> Mounting surface smooth, flat and greased		K/W
Mounting Super MAGN-A-PAK to heatsing	nk	A mounting compound is recommended and the torque should be rechecked after a period	6 to 8	Nm
torque busbar to super MAGN-A-PA	K	of 3 hours to allow for the spread of the compound	12 to 15	INIII
Approximate weight			1500	g
Case style		See dimensions (link at the end of datasheet)  Super N		-A-PAK

△R <sub>thJC</sub> CONDUCTIO	N			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006		
120°	0.011	0.011		
90°	0.014	0.015	$T_J = T_J$ maximum	K/W
60°	0.021	0.022		
30°	0.037	0.038		

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC





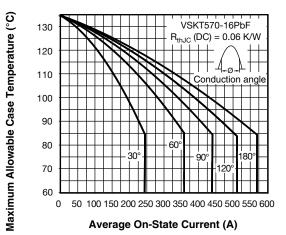


Fig. 1 - Current Ratings Characteristics

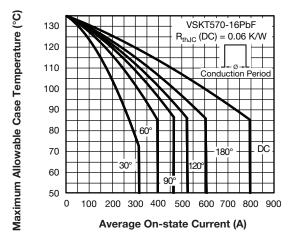


Fig. 2 - Current Ratings Characteristics

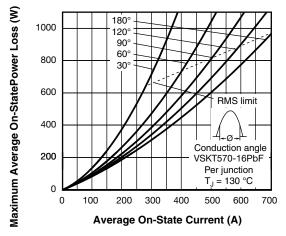


Fig. 3 - On-State Power Loss Characteristics

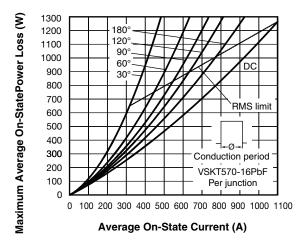


Fig. 4 - On-State Power Loss Characteristics

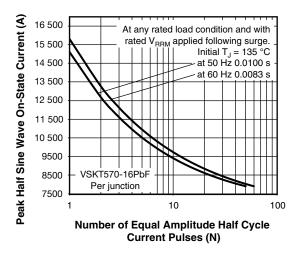


Fig. 5 - Maximum Non-Repetitive Surge Current

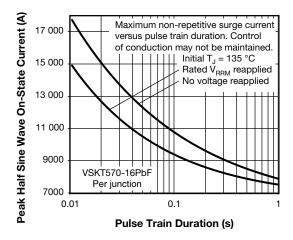
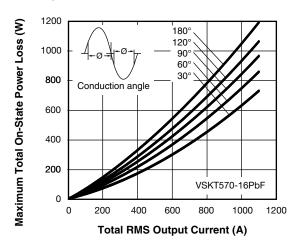


Fig. 6 - Maximum Non-Repetitive Surge Current

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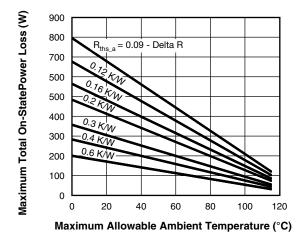


Fig. 7 - On-State Power Loss Characteristics

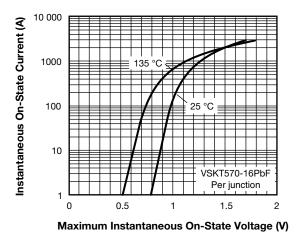


Fig. 8 - On-State Voltage Drop Characteristics

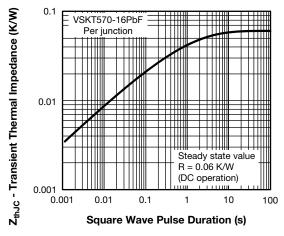


Fig. 9 - Thermal Impedance  $Z_{th\ensuremath{\text{JC}}}$  Characteristics

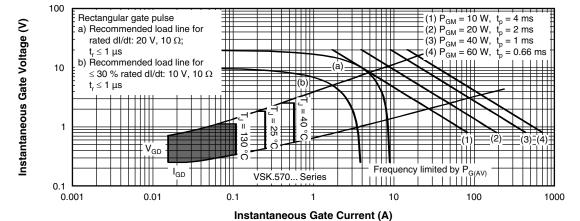
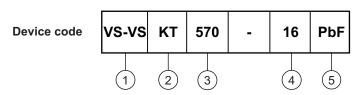


Fig. 10 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**



Vishay Semiconductors product

2 - Circuit configuration (see below)

Current rating

- Voltage code x 100 = V<sub>RRM</sub>

5 - Lead (Pb)-free

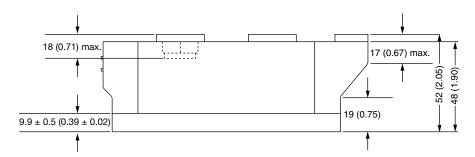
CIRCUIT CONFIGURATION				
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two SCRs doubler circuit	KT	VSKT  1 2 4 (K1) 7 (K2) 0 5 (G1) 6 (G2)		

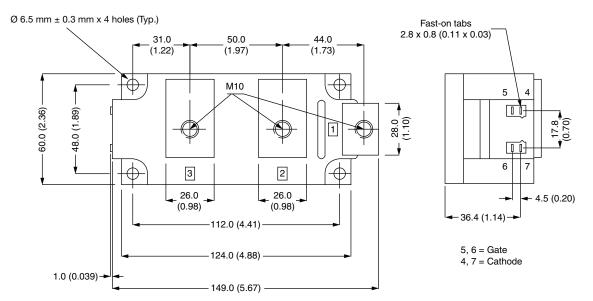
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95283



# **Super MAGN-A-PAK Thyristor/Diode**

#### **DIMENSIONS** in millimeters (inches)









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